



# BME 202 Electronics

## Lecture 12: FET Amplifiers

# Introduction

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## FETs provide:

- Excellent voltage gain
- High input impedance
- Low-power consumption
- Good frequency response

# FET Small-Signal Model

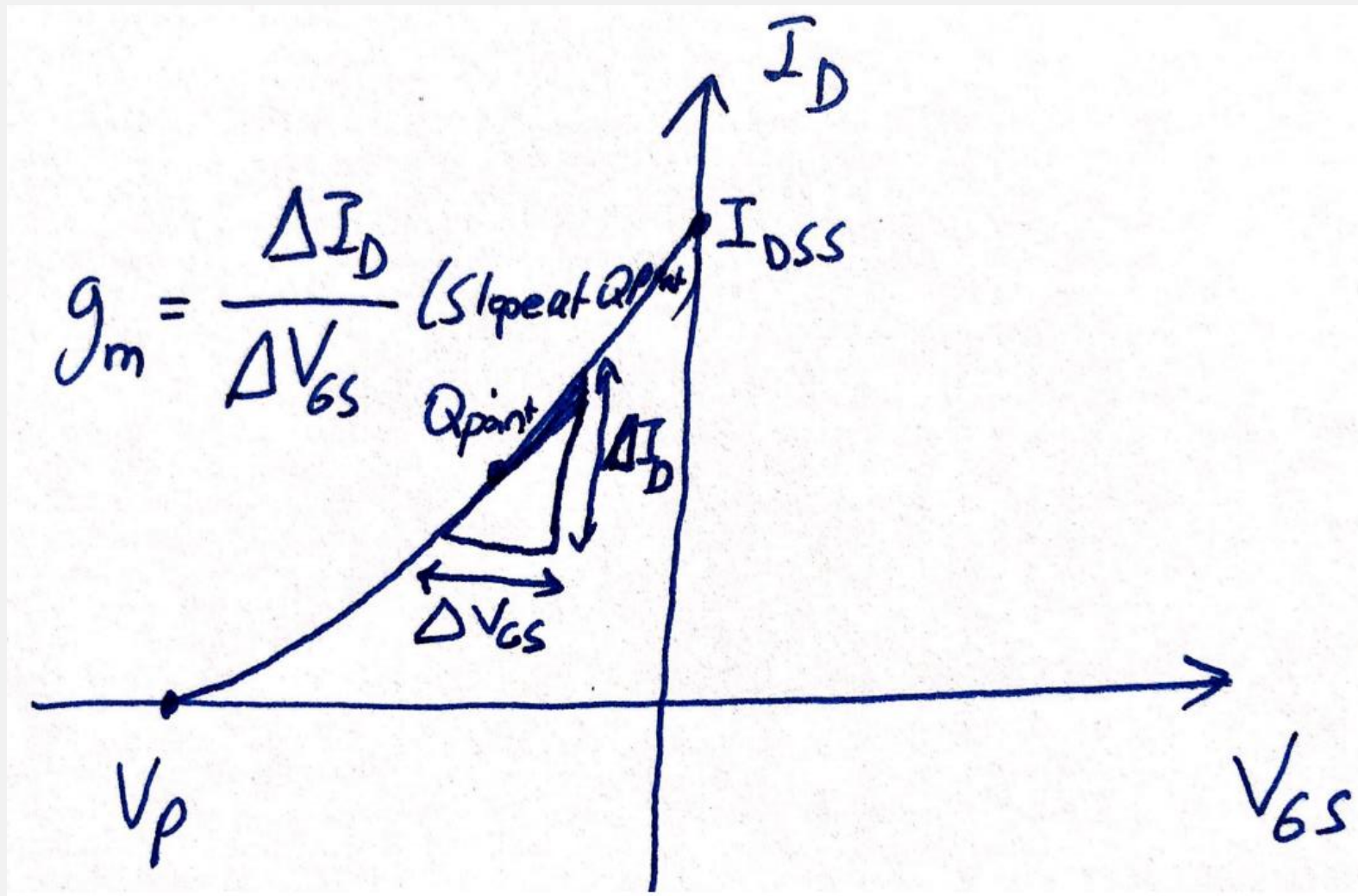
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*Transconductance:* The ratio of a change in  $I_D$  to the corresponding change in  $V_{GS}$

Transconductance is denoted  $g_m$  and given by:

$$g_m = \frac{\Delta I_D}{\Delta V_{GS}}$$

# Geographical Determination of gm



# Mathematical Definitions of $g_m$

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$$g_m = \frac{\Delta I_D}{\Delta V_{GS}}$$

$$g_m = \frac{2I_{DSS}}{|V_P|} \left[ 1 - \frac{V_{GS}}{V_P} \right]$$

For  $V_{GS} = 0 \text{ V}$

$$g_{m0} = \frac{2I_{DSS}}{|V_P|}$$

$$g_m = g_{m0} \left[ 1 - \frac{V_{GS}}{V_P} \right] = g_{m0} \sqrt{\frac{I_D}{I_{DSS}}}$$

# FET Impedance

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Input impedance:

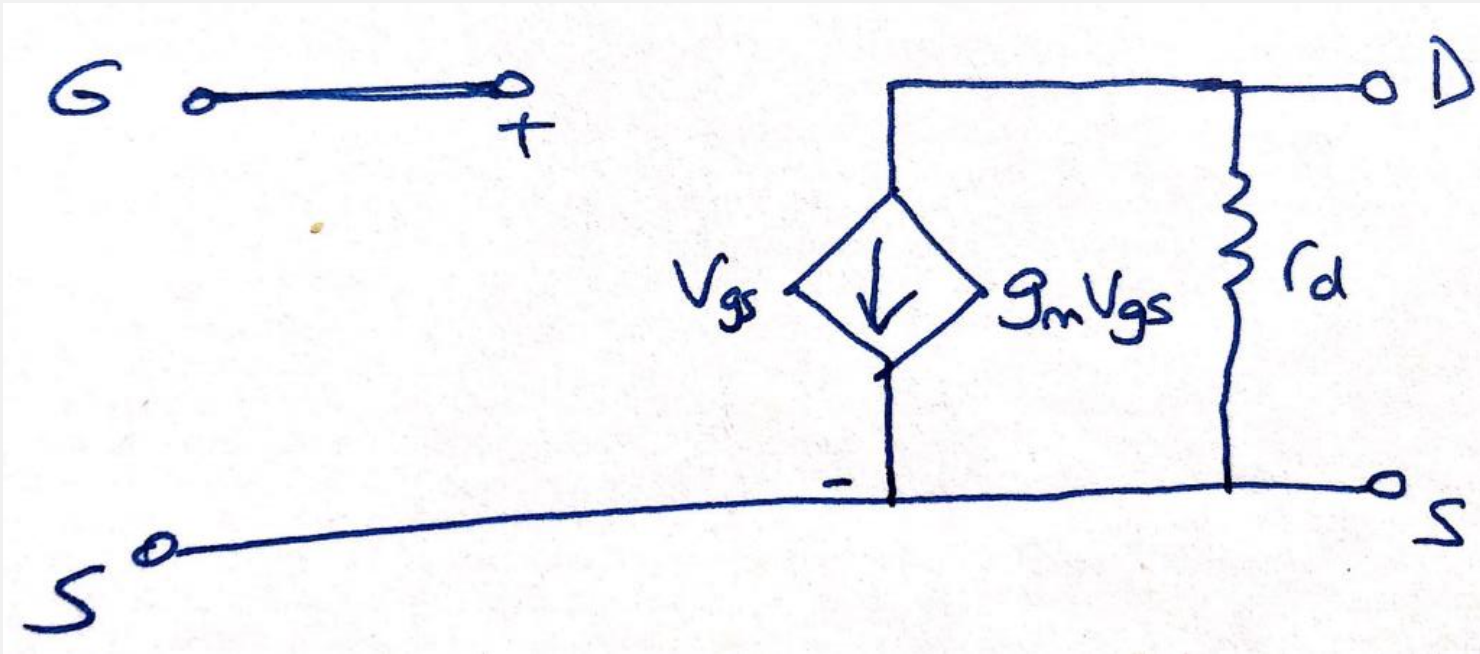
$$Z_i = \infty \Omega$$

Output Impedance:

$$Z_o = r_d = \frac{1}{y_{os}} \quad \text{where} \quad r_d = \left. \frac{\Delta V_{DS}}{\Delta I_D} \right|_{V_{GS} = \text{constant}}$$

$y_{os}$  = admittance parameter listed on FET spec sheets

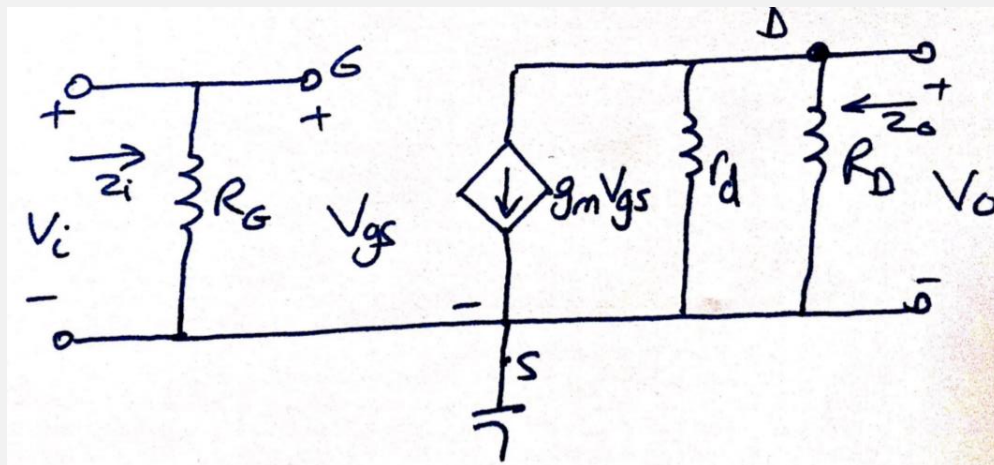
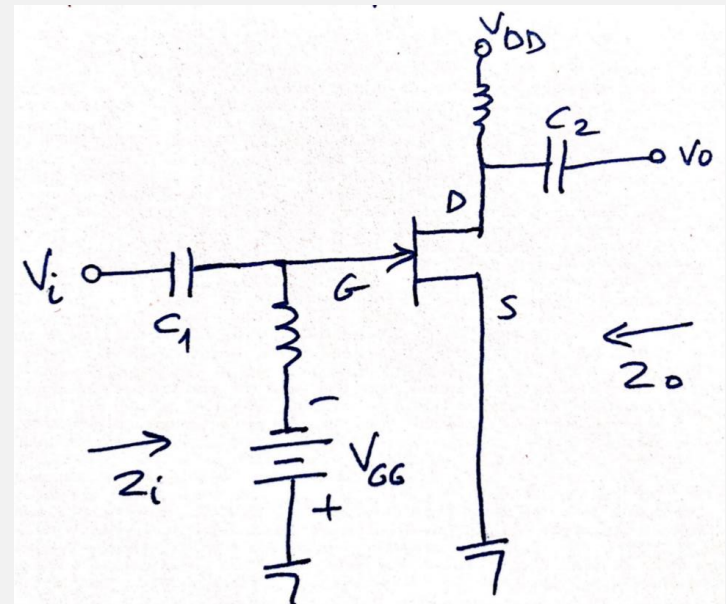
# FET AC Equivalent Circuit



# Common-Source (CS) Fixed-Bias

The input is applied to the gate and the output is taken from the drain

There is a  $180^\circ$  phase shift between the circuit input and output





# Calculations

Input impedance:

$$Z_i = R_G$$

Output impedance:

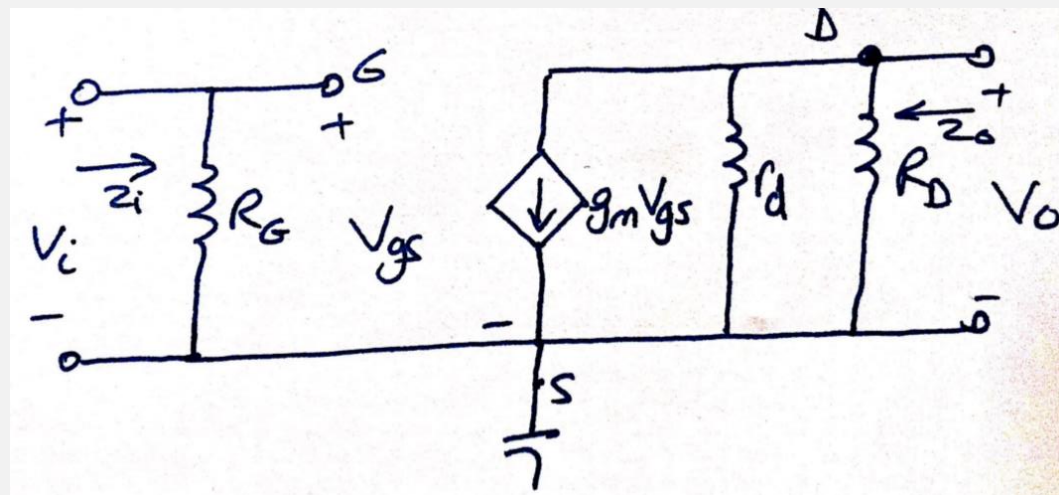
$$Z_o = R_D \parallel r_d$$

$$Z_o \cong R_D \Big|_{r_d \geq 10R_D}$$

Voltage gain:

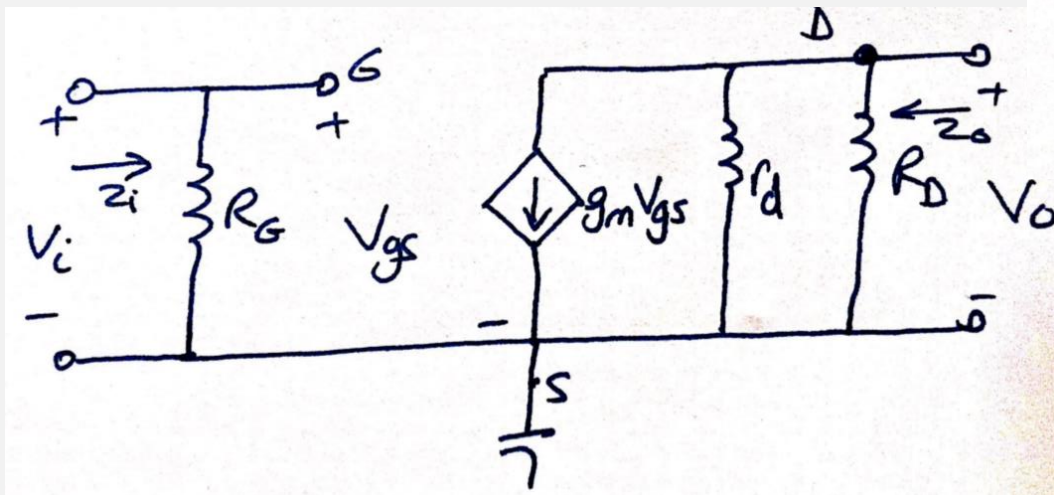
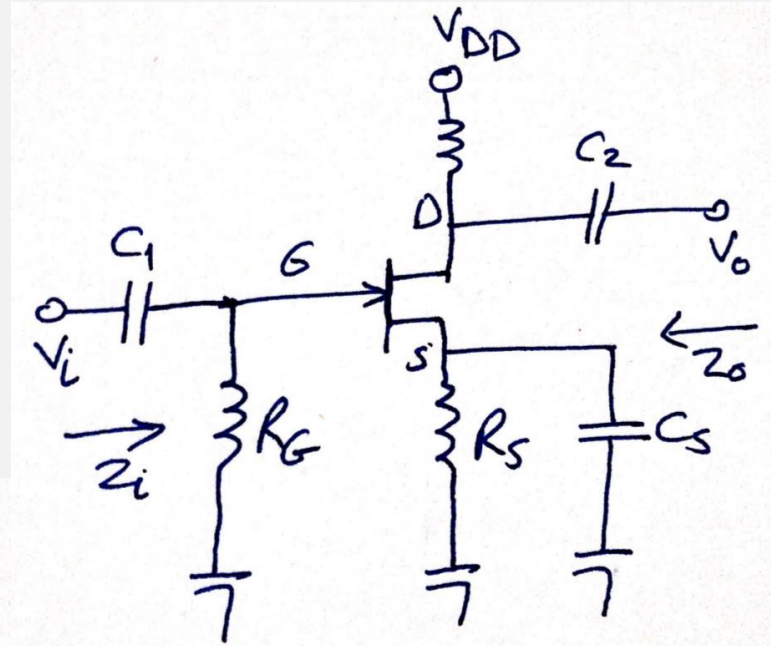
$$A_v = \frac{V_o}{V_i} = -g_m (r_d \parallel R_D)$$

$$A_v = \frac{V_o}{V_i} = -g_m R_D \Big|_{r_d \geq 10R_D}$$



# Common-Source (CS) Self-Bias

This is a common-source amplifier configuration, so the input is applied to the gate and the output is taken from the drain.



There is a  $180^\circ$  phase shift between input and output.

# Calculations

Input impedance:

$$Z_i = R_G$$

Output impedance:

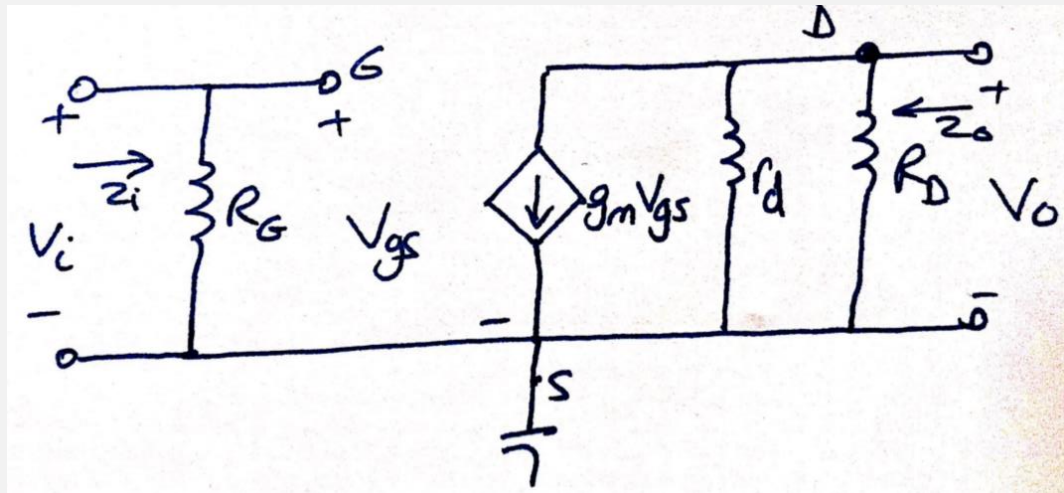
$$Z_o = r_d \parallel R_D$$

$$Z_o \cong R_D \Big|_{r_d \geq 10R_D}$$

Voltage gain:

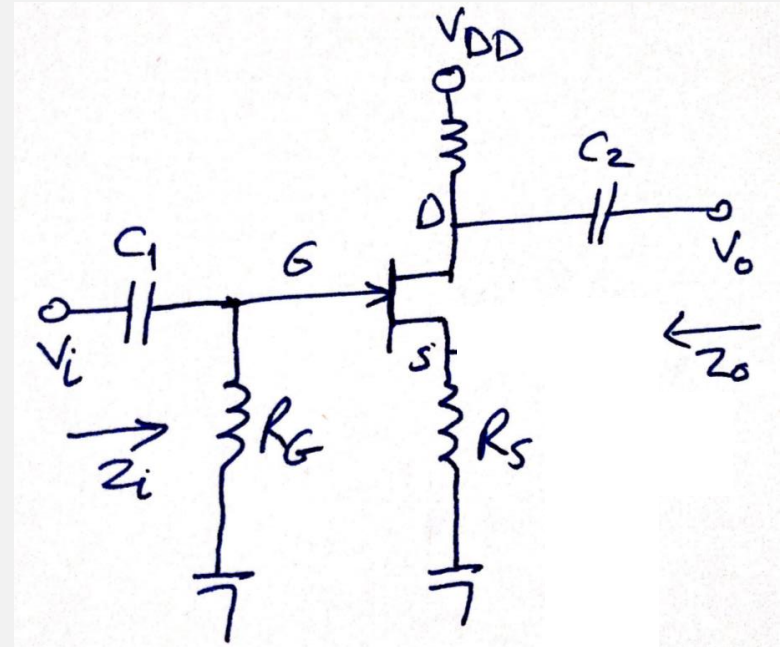
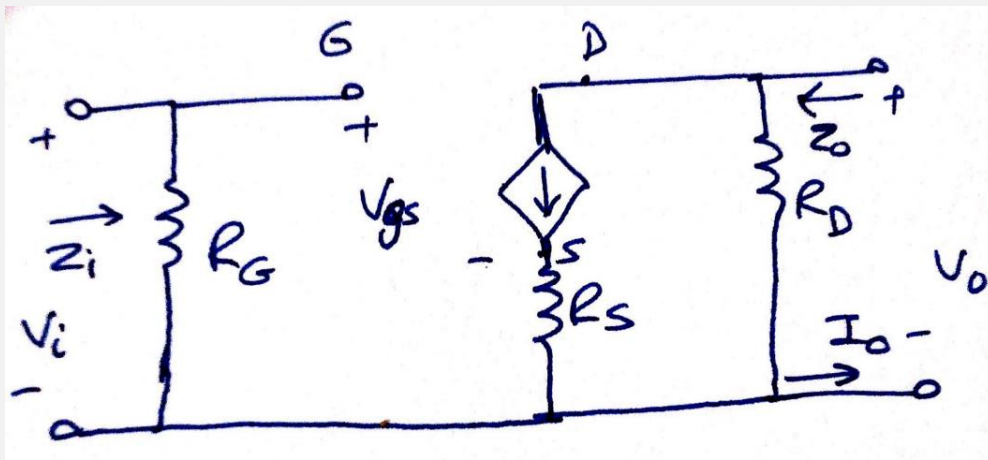
$$A_v = -g_m (r_d \parallel R_D)$$

$$A_v = -g_m R_D \Big|_{r_d \geq 10R_D}$$



# Common-Source (CS) Self-Bias

Removing  $C_s$  affects the gain of the circuit.



# Calculations

Input impedance:

$$Z_i = R_G$$

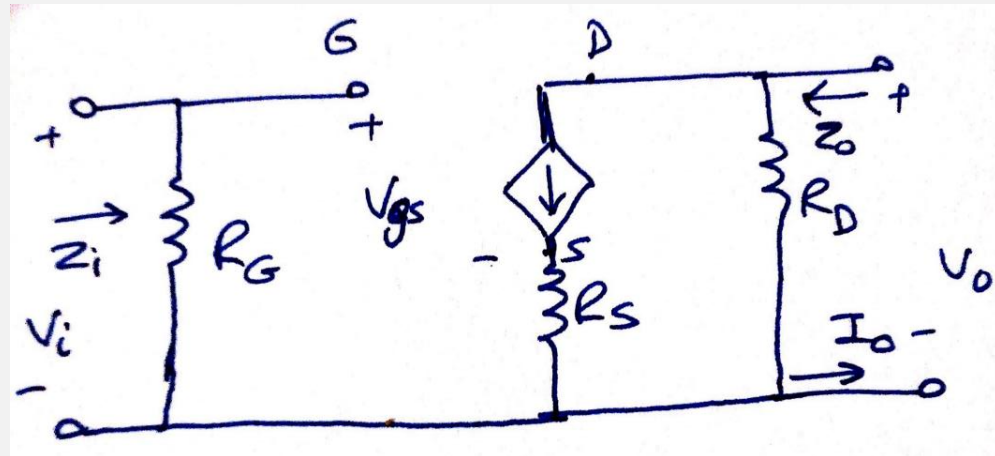
Output impedance:

$$Z_o \cong R_D \Big|_{r_d \geq 10R_D}$$

Voltage gain:

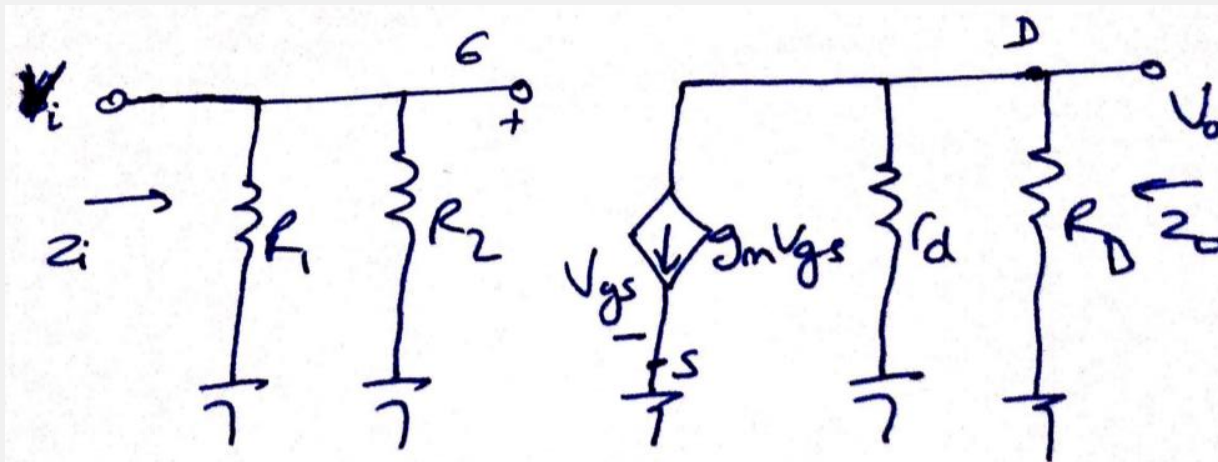
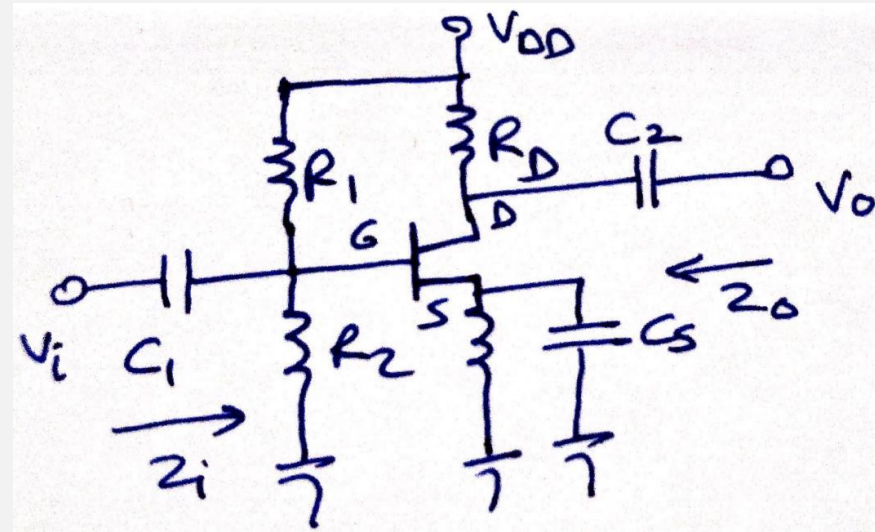
$$A_v = \frac{V_o}{V_i} = - \frac{g_m R_D}{1 + g_m R_S + \frac{R_D + R_S}{r_d}}$$

$$A_v = \frac{V_o}{V_i} = - \frac{g_m R_D}{1 + g_m R_S} \Big|_{r_d \geq 10(R_D + R_S)}$$



# Common-Source (CS) Voltage-Divider Bias

This is a common-source amplifier configuration, so the **input** is applied to the **gate** and the **output** is taken from the **drain**.



# Impedances

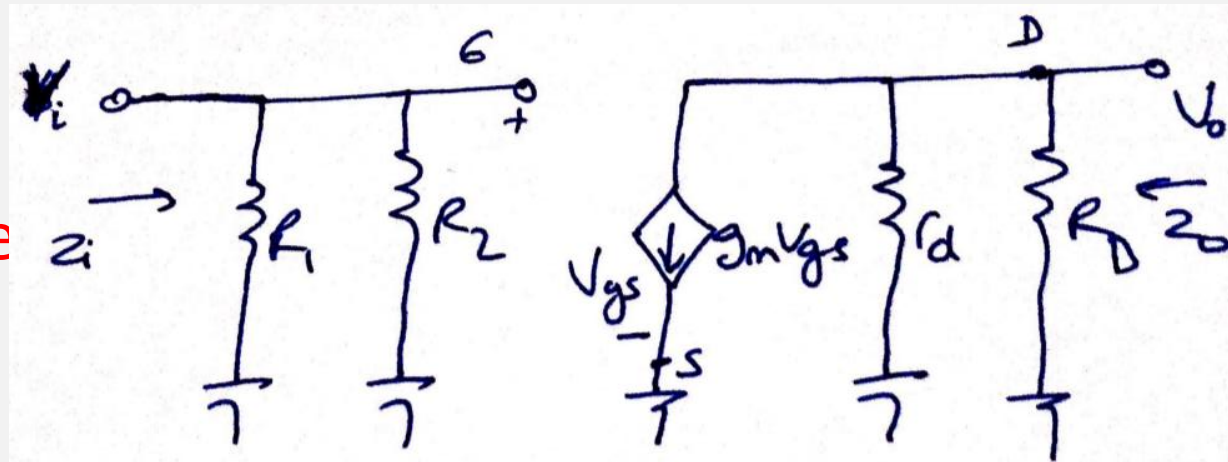
Input impedance:

$$Z_i = R_1 \parallel R_2$$

Output impedance

$$Z_o = r_d \parallel R_D$$

$$Z_o \cong R_D \Big|_{r_d \geq 10R_D}$$



Voltage gain:

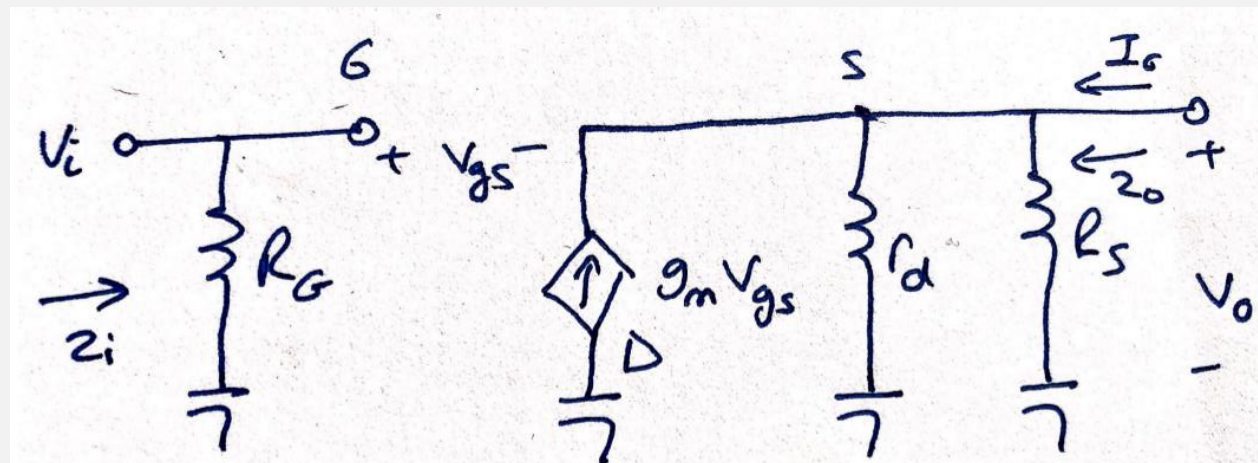
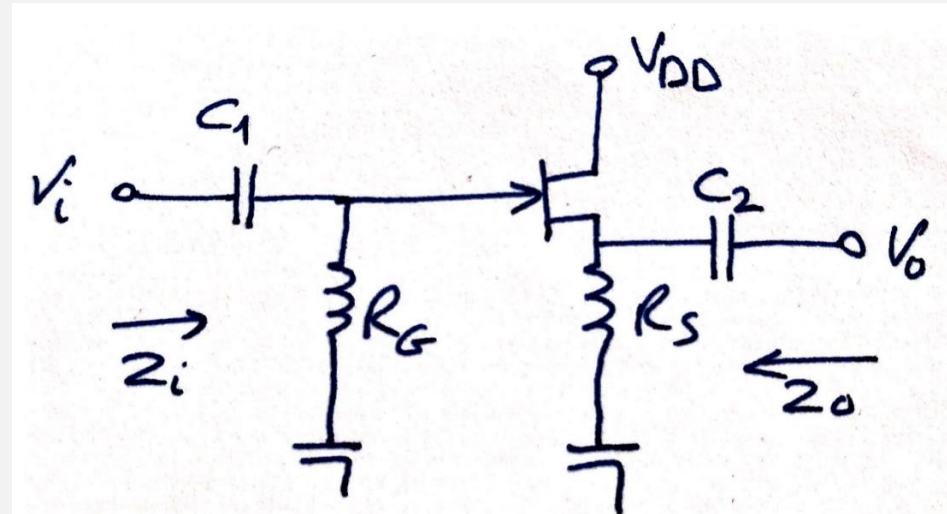
$$A_v = -g_m (r_d \parallel R_D)$$

$$A_v = -g_m R_D \Big|_{r_d \geq 10R_D}$$

# Source Follower (Common-Drain)

In a common-drain amplifier configuration, the input is applied to the gate, but the output is taken from the source.

There is no phase shift between input and output.





# Impedances

Input impedance:

$$Z_i = R_G$$

Output impedance:

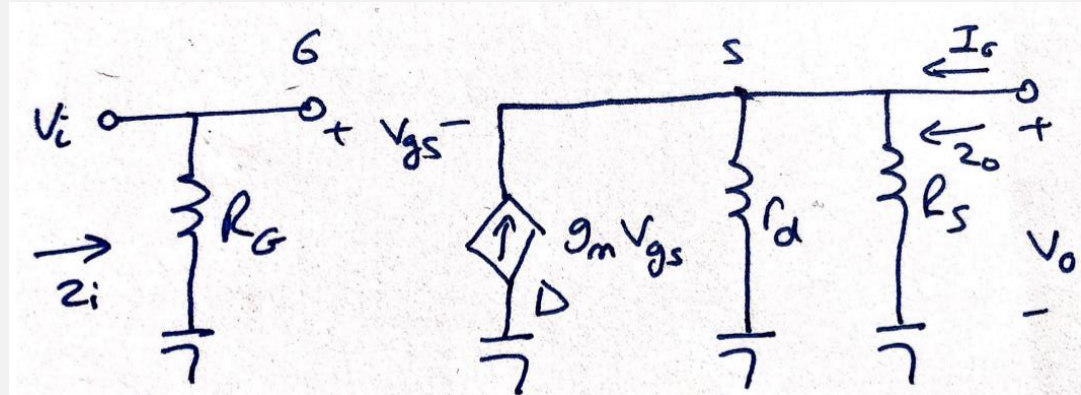
$$Z_o = r_d \parallel R_S \parallel \frac{1}{g_m}$$

$$Z_o \cong R_S \parallel \frac{1}{g_m} \Big|_{r_d \geq 10R_S}$$

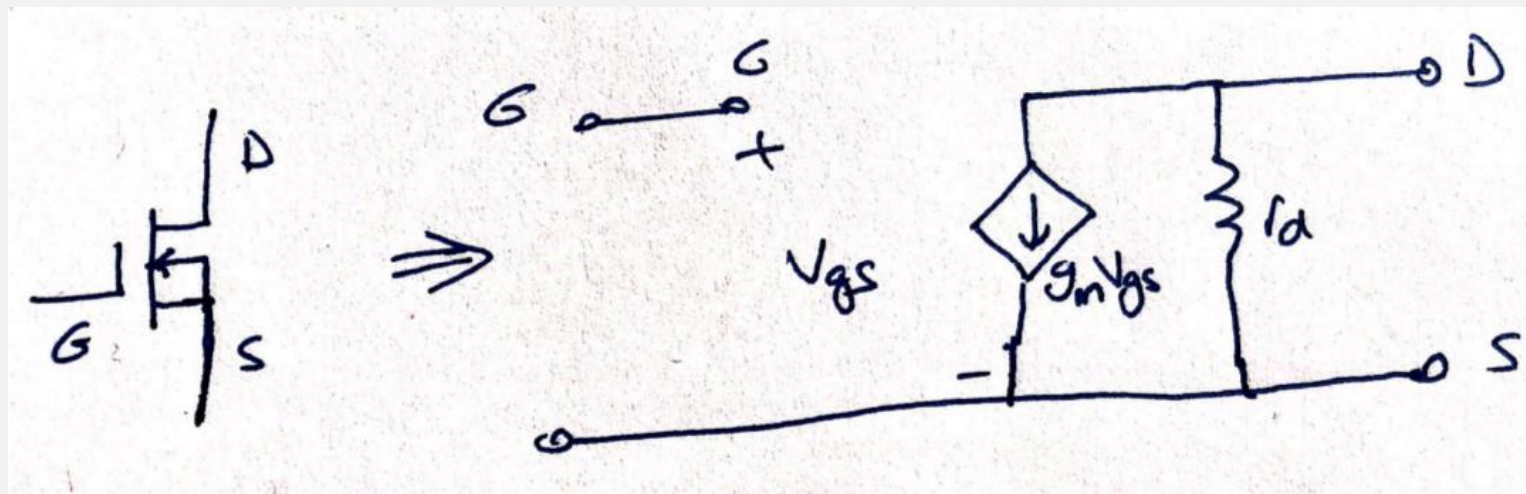
Voltage gain:

$$A_v = \frac{V_o}{V_i} = \frac{g_m (r_d \parallel R_S)}{1 + g_m (r_d \parallel R_S)}$$

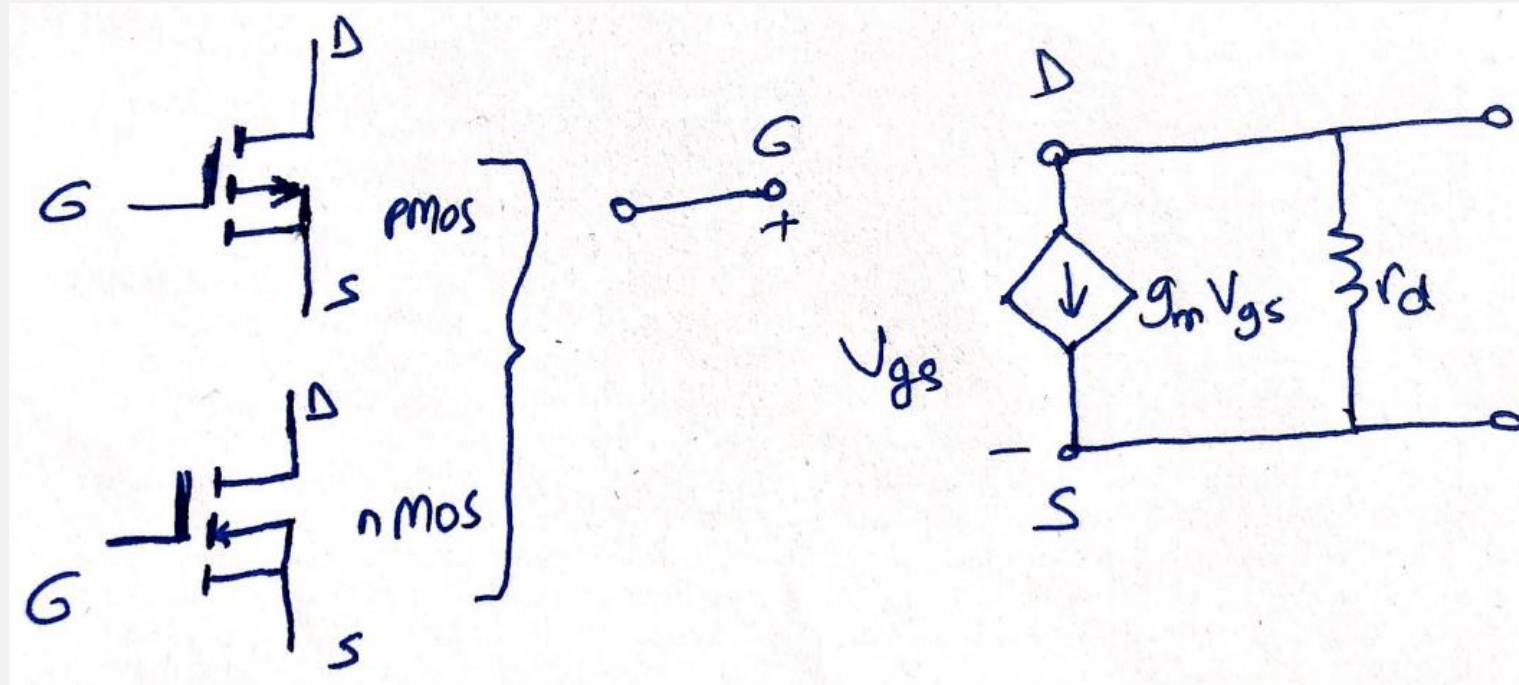
$$A_v = \frac{V_o}{V_i} = \frac{g_m R_S}{1 + g_m R_S} \Big|_{r_d \geq 10R_S}$$



# D-Type MOSFET AC Equivalent



# E-Type MOSFET AC Equivalent



$g_m$  and  $r_d$  can be found in the specification sheet for the FET.

# Troubleshooting

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## Check the DC bias voltages:

If not correct check power supply, resistors, FET. Also check to ensure that the coupling capacitor between amplifier stages is OK.

## Check the AC voltages:

If not correct check FET, capacitors and the loading effect of the next stage

# Practical Applications

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- Three-Channel Audio Mixer
- Silent Switching
- Phase Shift Networks
- Motion Detection System